SDAS027B - APRIL 1984 - REVISED JANUARY 1995

- 3-State I/O-Type Read-Back Inputs
- Bus-Structured Pinout
- True Logic Outputs
- Package Options Include Plastic Small-Outline (DW) Packages and Standard Plastic (N) 300-mil DIPs

#### description

This 8-bit latch is designed specifically for storing the contents of the input data bus and providing the capability of reading back the stored data onto the input data bus.

The eight latches are transparent D-type latches. While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs.

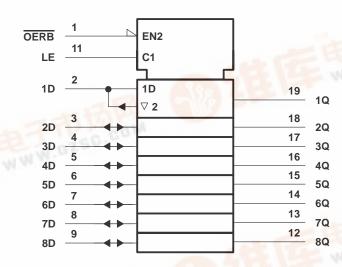
DW OR N PACKAGE (TOP VIEW)

		I
1	20	
2	19	
3	18	
4		
5		
6	15	] 5Q
7	14	
8		
9	12	
10	11	LE
	3 4 5 6 7 8 9	3 18 4 17 5 16 6 15 7 14 8 13 9 12

Read back is provided through the output-enable (OERB) input. When OERB is taken low, the data present at the output of the data latches is allowed to pass back onto the input data bus. When OERB is taken high, the output of the data latches is isolated from the D inputs. OERB does not affect the internal operation of the latches; however, precautions should be taken not to create a bus conflict.

The SN74ALS990 is characterized for operation from 0°C to 70°C.

## logic symbol†



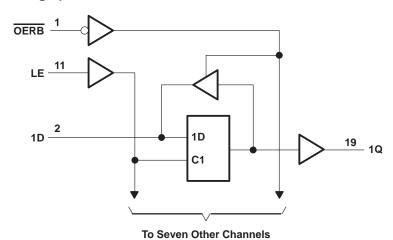
† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



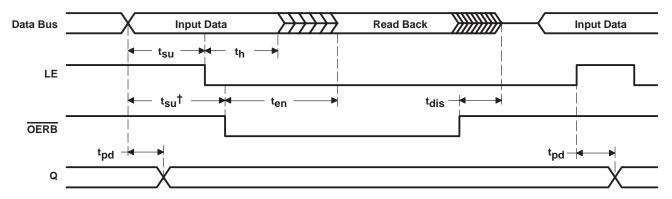


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## logic diagram (positive logic)



### timing diagram



<sup>†</sup> This setup time ensures that the read-back circuit will not create a conflict on the input data bus.

# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage, V <sub>CC</sub>	7 V
Input voltage, V <sub>I</sub> (OERB and LE)	7 V
Voltage applied to D inputs	5.5 V
Operating free-air temperature range, T <sub>A</sub>	0°C to 70°C
Storage temperature range	-65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



## **SN74ALS990** 8-BIT D-TYPE TRANSPARENT READ-BACK LATCH

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## recommended operating conditions

			MIN	NOM	MAX	UNIT	
V <sub>CC</sub> Supply voltage		4.5	5	5.5	V		
V <sub>IH</sub> High-level input voltage		2			V		
VIL	V <sub>IL</sub> Low-level input voltage				0.8	V	
IOH High-level output current	High level output current	Q			-2.6	mA	
	riigii-ievei output current	D			-0.4		
IOL Low-level output current	Low level output ourrent	Q			24		
	D			8	mA		
t <sub>W</sub> Pulse duration, LE high		10			ns		
	Saturations	Data before LE↓	10			ns	
t <sub>SU</sub> Setup time	Setup time	Data before OERB↓	10				
$t_h$ Hold time, data after LE $\downarrow$		5			ns		
TA	Operating free-air temperature		0		70	°C	

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

F	PARAMETER	TEST CON	DITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT
VIK		V <sub>CC</sub> = 4.5 V,	$I_{I} = -18 \text{ mA}$			-1.2	V
Vон	All outputs	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -0.4 \text{ mA}$	V <sub>CC</sub> -2			V
	Q	V <sub>CC</sub> = 4.5 V,	$I_{OH} = -2.6 \text{ mA}$	2.4	3.2		
	D V 45	V 45V	I <sub>OL</sub> = 4 mA		0.25	0.4	,
\/	D	V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 8 mA		0.35	0.5	
VOL	Q V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 12 mA		0.25	0.4	V	
		I <sub>OL</sub> = 24 mA		0.35	0.5		
	OERB, LE	V-2 F-V	V <sub>I</sub> = 5.5 V			0.1	mA
li l	D inputs	V <sub>I</sub> = 7 V			0.1	mA	
	OERB, LE	V00 - 55 V	\\ 2.7.\\			20	
lн	D inputs <sup>‡</sup>	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 2.7 V			20	μΑ
ſ	OERB, LE	V	\\ 0.4 \\			-0.1	A
IIL	D inputs <sup>‡</sup>	inputs <sup>‡</sup> $V_{CC} = 5.5 \text{ V}, V_{I}$	V <sub>I</sub> = 0.4 V			-0.1	mA
IO§		V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.25 V	-30		-112	mA
Icc	$\frac{V_{CC}}{OERB}$ high	Outputs high		27	50	mA	
		Outputs low		40	70	] ""A	



<sup>†</sup> All typical values are at  $V_{CC}$  = 5 V,  $T_A$  = 25°C. ‡ For I/O ports ( $Q_A$  thru  $Q_H$ ), the parameters  $I_{IH}$  and  $I_{IL}$  include the off-state output current.

<sup>§</sup> The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

## **SN74ALS990** 8-BIT D-TYPE TRANSPARENT READ-BACK LATCH

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## switching characteristics (see Figure 1)

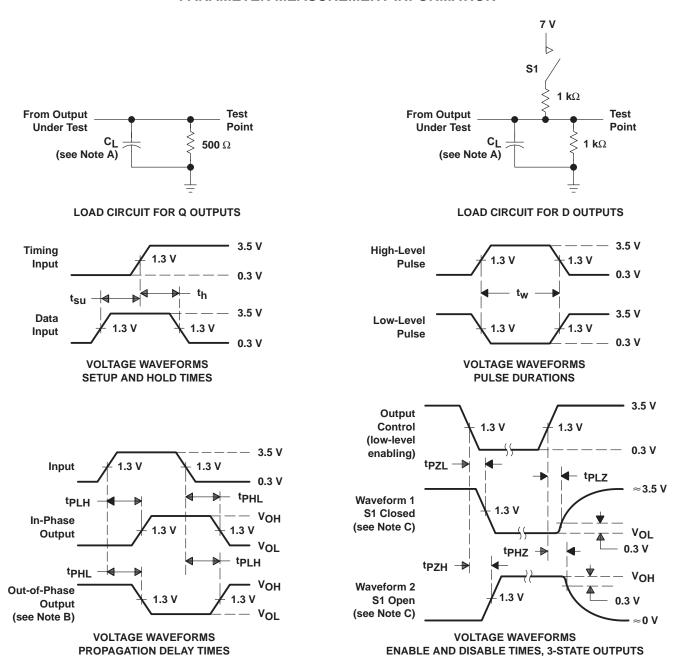
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$ $C_L = 50 \text{ pF},$ $T_A = \text{MIN to MAX}^{\dagger}$		UNIT
			MIN	MAX	
<sup>t</sup> PLH	D		4	17	ne
<sup>t</sup> PHL	J J	Q	5	24	ns
<sup>t</sup> PLH	LE		6	26	ns
<sup>t</sup> PHL	LE	Q	8	26	115
t <sub>en</sub> ‡	OERB	D	4	21	ns
t <sub>dis</sub> §	OERB	D	4	19	ns

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ ten = tpzH or tpzL

§ tdis = tpHz or tpLz

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. When measuring propagation delay times of 3-state outputs, switch S1 is open.
- C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- D. All input pulses have the following characteristics: PRR  $\leq$  1 MHz,  $t_{\Gamma} = t_{\tilde{\Gamma}} = 2$  ns, duty cycle = 50%.

Figure 1. Load Circuits and Voltage Waveforms



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